

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

*Note:*

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>					
Thermal Resistance (°C/W)					
Junction to	Ambient Mosfet	Ambient Schottky	Case	Foot Mosfet	Foot Schottky
RT1	5.7407	18.5197	N/A	12.8956	14.4852
RT2	22.4526	17.2773	N/A	3.7536	7.2459
RT3	35.2874	35.4608	N/A	13.1181	9.9573
RT4	46.5193	43.7422	N/A	10.2327	15.3116
Thermal Capacitance (Joules/°C)					
Junction to	Ambient Mosfet	Ambient Schottky	Case	Foot Mosfet	Foot Schottky
CT1	391.8258 u	64.9041 u	N/A	134.3353 m	92.0114 m
CT2	7.3908 m	3.6401 m	N/A	297.7361 u	48.6379 u
CT3	50.6844 m	31.3345 m	N/A	5.1404 m	666.1825 u
CT4	1.3716	1.2455	N/A	43.7374 m	6.9648 m

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ( $^{\circ}\text{C}/\text{W}$ )					
Junction to	Ambient Mosfet	Ambient Schottky	Case	Foot Mosfet	Foot Schottky
RF1	7.7511	20.4519	N/A	3.9925	8.2309
RF2	27.1046	24.8031	N/A	4.7093	11.3266
RF3	31.3650	28.6084	N/A	14.1123	16.4593
RF4	43.7793	41.1366	N/A	17.1859	10.9832
Thermal Capacitance (Joules/ $^{\circ}\text{C}$ )					
Junction to	Ambient Mosfet	Ambient Schottky	Case	Foot Mosfet	Foot Schottky
CF1	487.2994 u	68.4422 u	N/A	306.3353 u	44.5285 u
CF2	6.6929 m	4.6669 m	N/A	2.1131 m	601.0970 u
CF3	47.9992 m	41.6149 m	N/A	3.9615 m	7.1072 m
CF4	1.4035	1.2936	N/A	58.8460 m	125.3721 m

Note: NA indicates not applicable

## Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002



